



# PBSS4021PX-Q

20 V, 6.2 A PNP low V<sub>CEsat</sub> transistor

9 January 2025

Product data sheet

## 1. General description

PNP low V<sub>CEsat</sub> transistor in a medium power and flat lead SOT89 (SC-62) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4021NX-Q

## 2. Features and benefits

- Very low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- High energy efficiency due to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-6.2	A
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-15	A
R <sub>CEsat</sub>	collector-emitter saturation resistance	I <sub>C</sub> = -4 A; I <sub>B</sub> = -400 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	23	38	mΩ

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	<p>SOT89</p>	<p>006aaa231</p>
2	C	collector		
3	B	base		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
<a href="#">PBSS4021PX-Q</a>	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<a href="#">SOT89</a>

## 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS4021PX-Q	%6E

[1] % = placeholder for manufacturing site code

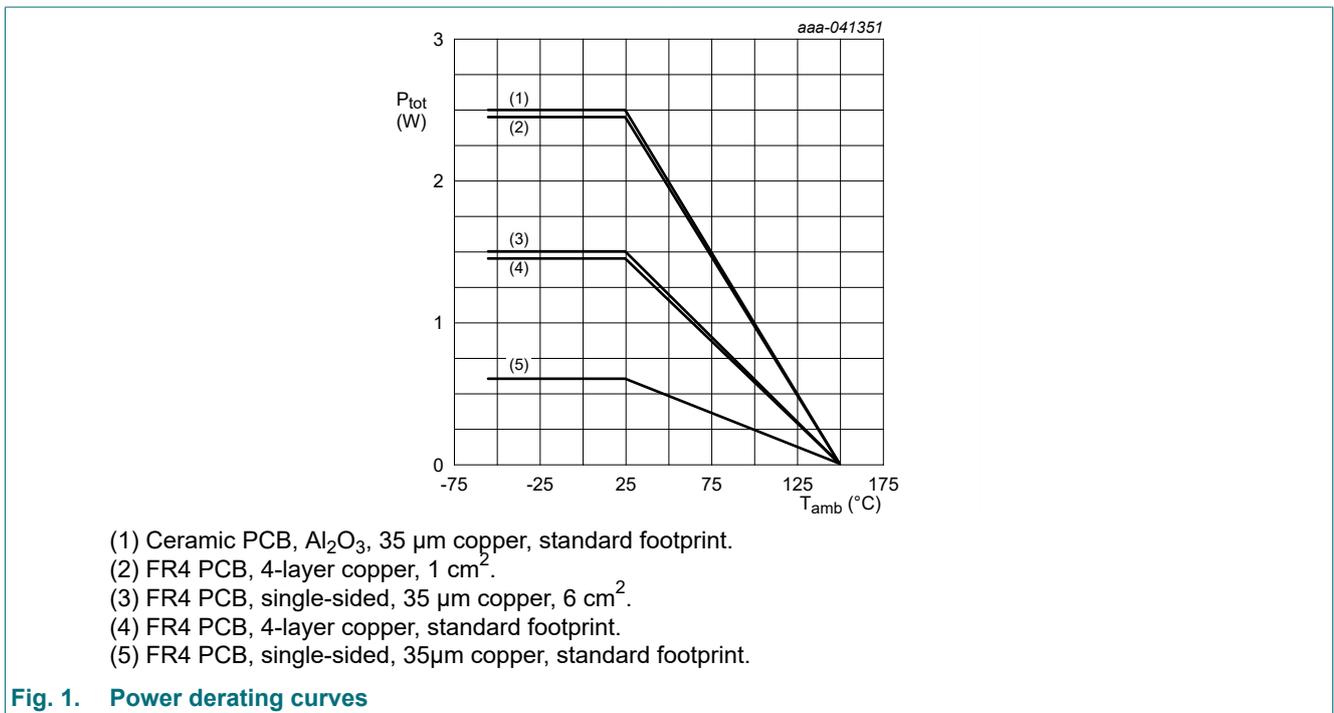
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-20	V
$V_{CEO}$	collector-emitter voltage	open base		-	-20	V
$V_{EBO}$	emitter-base voltage	open collector		-	-5	V
$I_C$	collector current			-	-6.2	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms		-	-15	A
$I_B$	base current			-	-1	A
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	600	mW
			[2]	-	1.5	W
			[3]	-	1.45	W
			[4]	-	2.45	W
			[5]	-	2.5	W
$T_j$	junction temperature			-	150	°C
$T_{amb}$	ambient temperature			-55	150	°C
$T_{stg}$	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35  $\mu$ m copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35  $\mu$ m copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [5] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, single-sided, 35  $\mu$ m copper, tin-plated and standard footprint.



**Fig. 1. Power derating curves**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	208	K/W
			[2]	-	-	83	K/W
			[3]	-	-	86	K/W
			[4]	-	-	51	K/W
			[5]	-	-	50	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided, 35  $\mu\text{m}$  copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35  $\mu\text{m}$  copper, tin-plated, mounting pad for collector 6  $\text{cm}^2$ .
- [3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1  $\text{cm}^2$ .
- [5] Device mounted on a ceramic PCB,  $\text{Al}_2\text{O}_3$ , single-sided, 35  $\mu\text{m}$  copper, tin-plated and standard footprint.

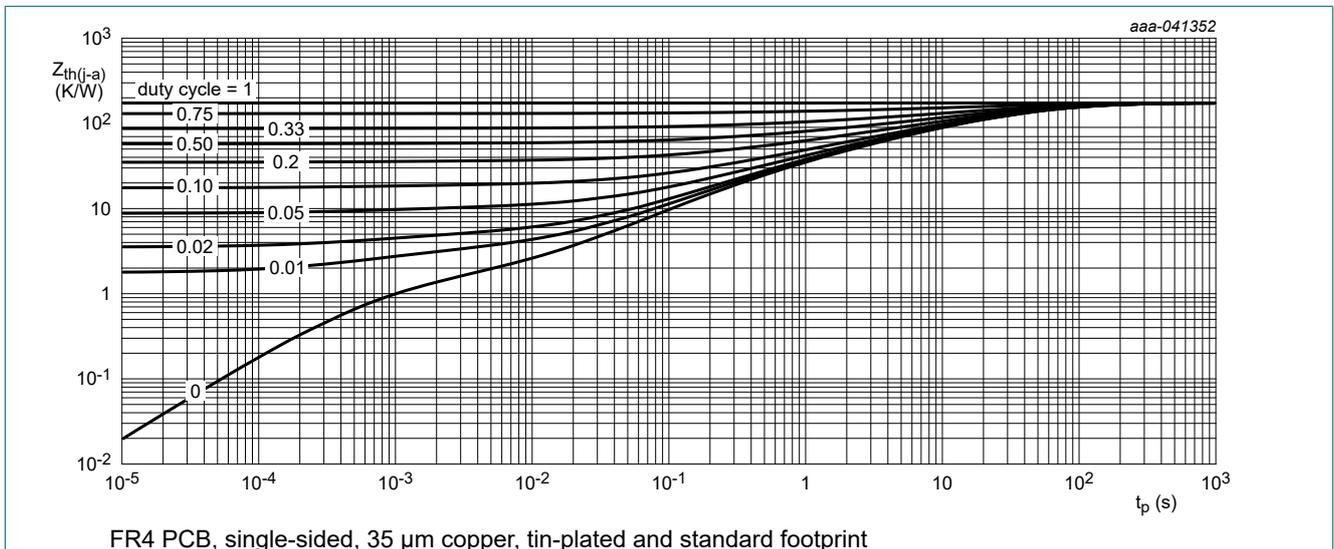


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

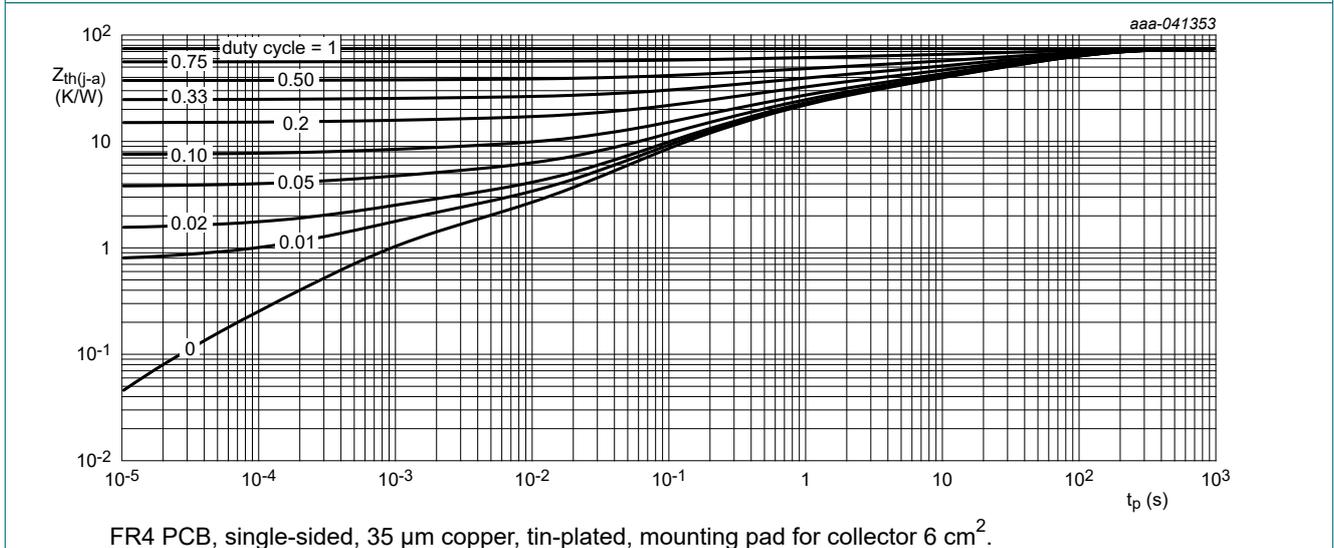
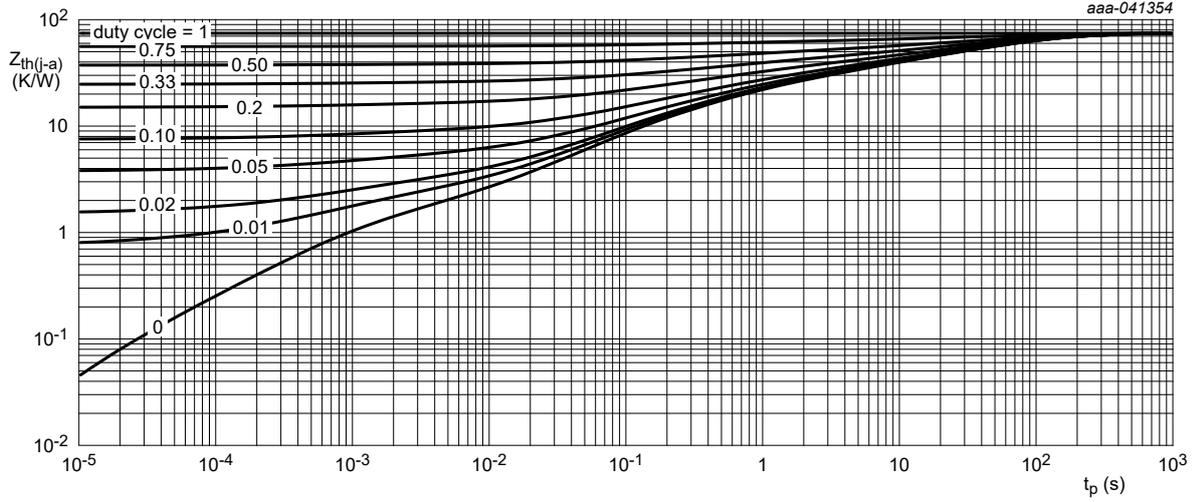
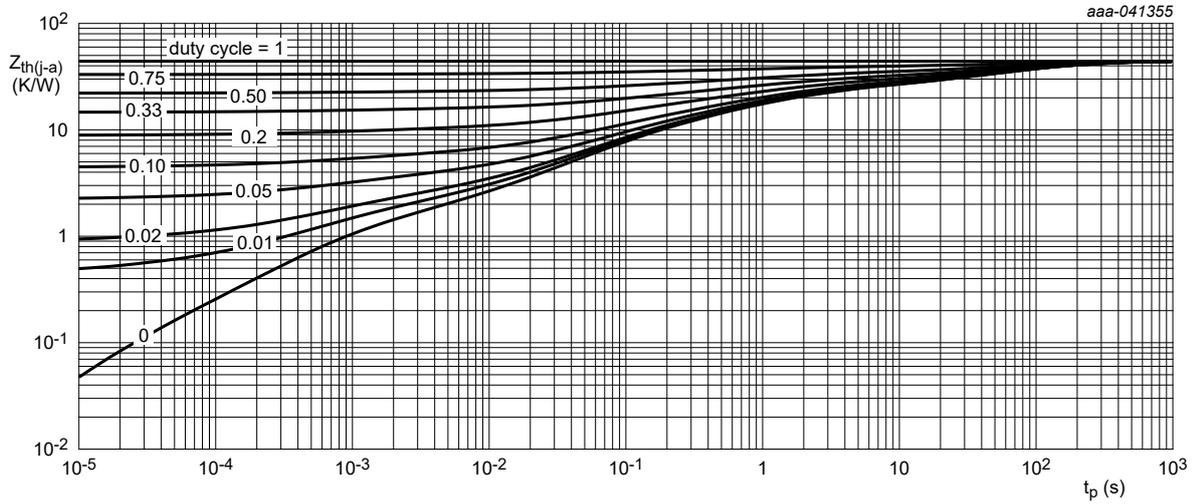


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



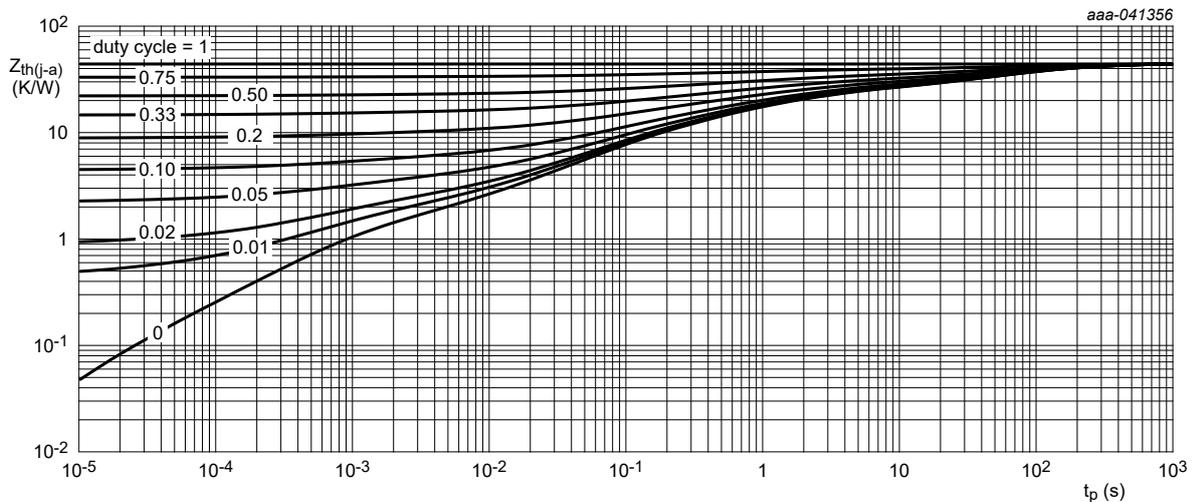
FR4 PCB, 4-layer 35  $\mu$ m copper, tin-plated and standard footprint.

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer 35  $\mu$ m copper, tin-plated, mounting pad for collector  $1\text{ cm}^2$ .

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB,  $\text{Al}_2\text{O}_3$ , single-sided, 35  $\mu$ m copper, tin-plated and standard footprint.

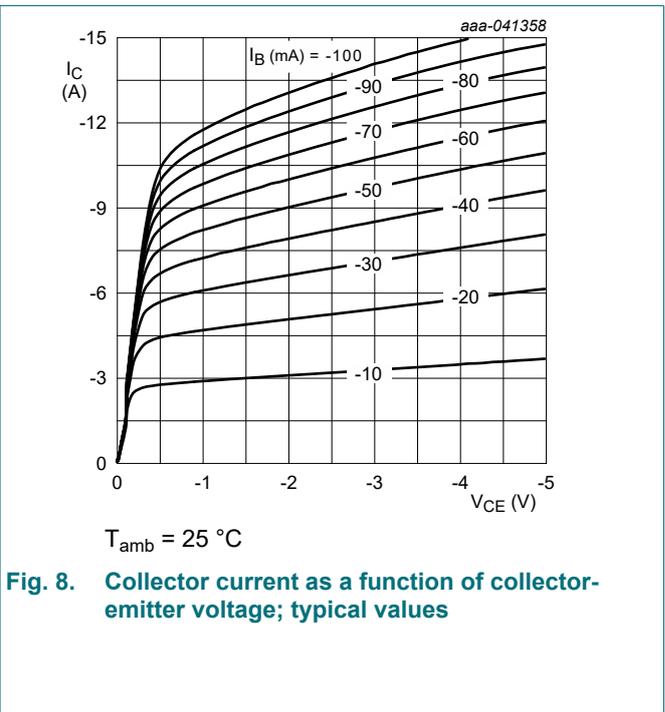
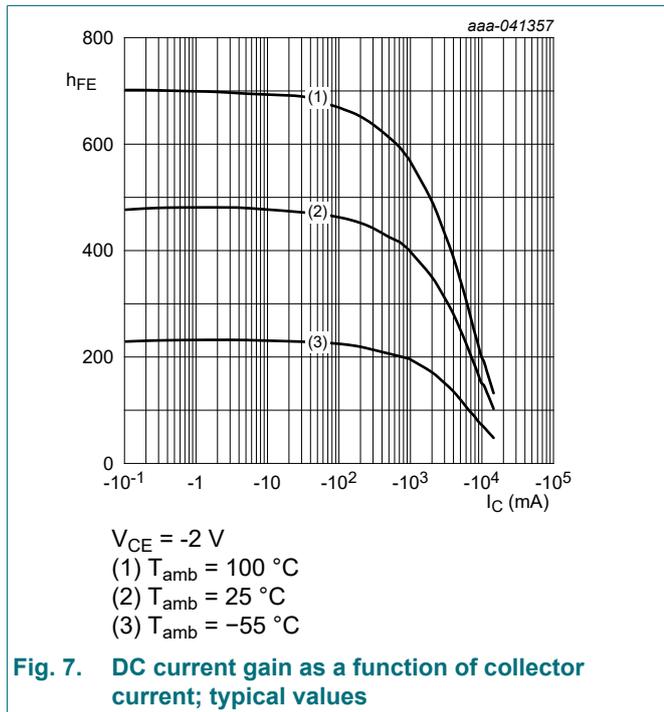
Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-20	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -10 \text{ mA}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-20	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = -100 \mu\text{A}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-5	-	-	V
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -20 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-100	nA
		$V_{CB} = -20 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$	-	-	-50	$\mu\text{A}$
$I_{CES}$	collector-emitter cut-off current	$V_{CE} = -16 \text{ V}$ ; $V_{BE} = 0 \text{ V}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-100	nA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = -5 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-100	nA
$h_{FE}$	DC current gain	$V_{CE} = -2 \text{ V}$ ; $I_C = -0.5 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	250	425	-	
		$V_{CE} = -2 \text{ V}$ ; $I_C = -1 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	250	405	-	
		$V_{CE} = -2 \text{ V}$ ; $I_C = -2 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	200	355	-	
		$V_{CE} = -2 \text{ V}$ ; $I_C = -4 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	150	290	-	
		$V_{CE} = -2 \text{ V}$ ; $I_C = -7 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	80	210	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -1 \text{ A}$ ; $I_B = -10 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-50	-90	mV
		$I_C = -1 \text{ A}$ ; $I_B = -50 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-30	-50	mV
		$I_C = -2 \text{ A}$ ; $I_B = -40 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-60	-110	mV
		$I_C = -4 \text{ A}$ ; $I_B = -40 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-130	-270	mV
		$I_C = -4 \text{ A}$ ; $I_B = -200 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-90	-160	mV
		$I_C = -6.9 \text{ A}$ ; $I_B = -345 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-160	-265	mV
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = -4 \text{ A}$ ; $I_B = -400 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	23	38	m $\Omega$
$V_{BEsat}$	base-emitter saturation voltage	$I_C = -1 \text{ A}$ ; $I_B = -100 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-0.82	-0.9	V
		$I_C = -4 \text{ A}$ ; $I_B = -400 \text{ mA}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-0.93	-1.05	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}$ ; $I_C = -2 \text{ A}$ ; pulsed; $t_p \leq 300 \mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-0.74	-0.85	V

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_d$	delay time	$V_{CC} = -12.5\text{ V}; I_C = -1\text{ A}; I_{B\text{on}} = -50\text{ mA};$ $I_{B\text{off}} = 50\text{ mA}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	43	-	ns
$t_r$	rise time		-	50	-	ns
$t_{\text{on}}$	turn-on time		-	93	-	ns
$t_s$	storage time		-	347	-	ns
$t_f$	fall time		-	87	-	ns
$t_{\text{off}}$	turn-off time		-	434	-	ns
$f_T$	transition frequency	$V_{CE} = -10\text{ V}; I_C = -100\text{ mA}; f = 100\text{ MHz};$ $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	91	-	MHz
$C_c$	collector capacitance	$V_{CB} = -10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A};$ $f = 1\text{ MHz}; T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	129	-	pF



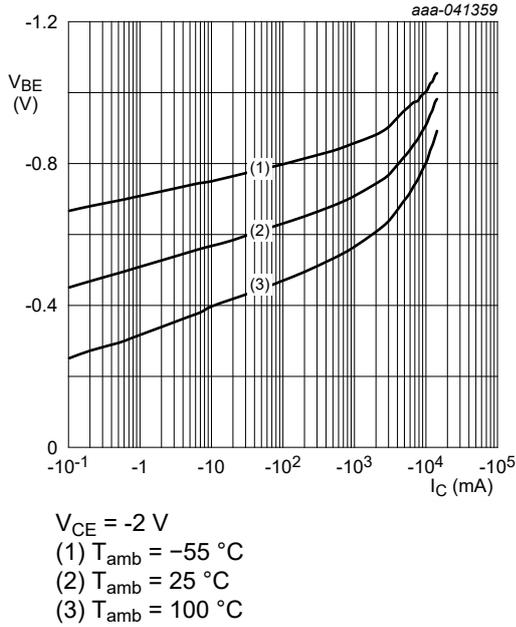


Fig. 9. Base-emitter voltage as a function of collector current; typical values

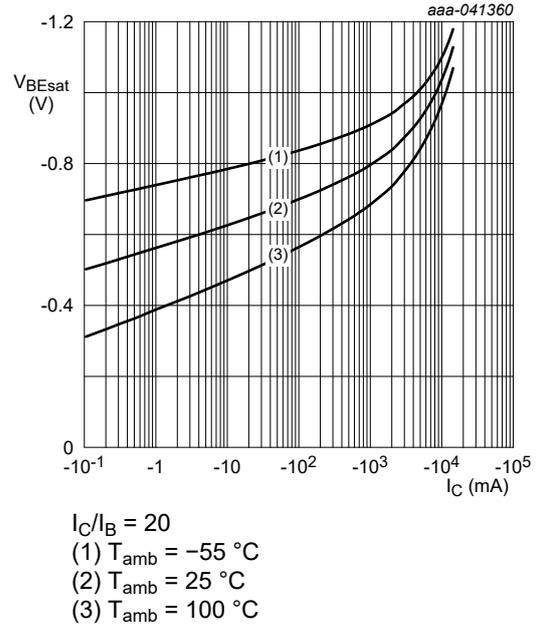


Fig. 10. Base-emitter saturation voltage as a function of collector current; typical values

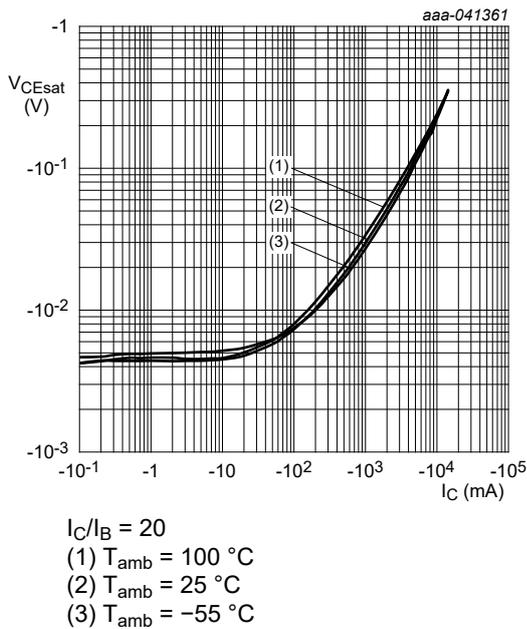


Fig. 11. Collector-emitter saturation voltage as a function of collector current; typical values

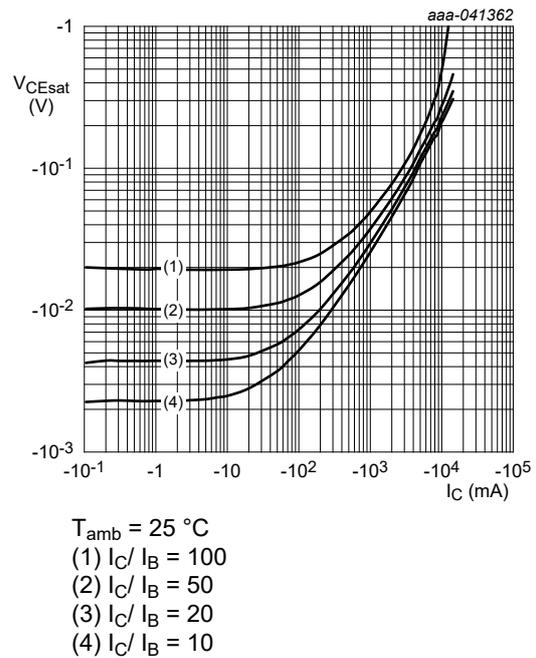
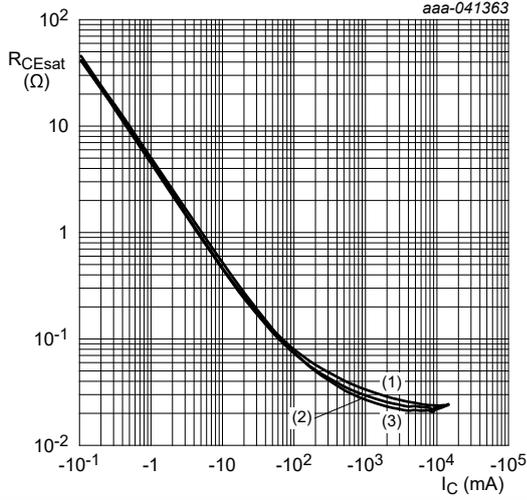
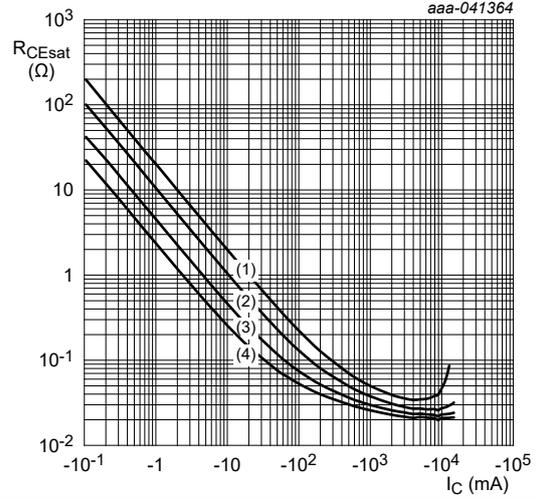


Fig. 12. Collector-emitter saturation voltage as a function of collector current; typical values



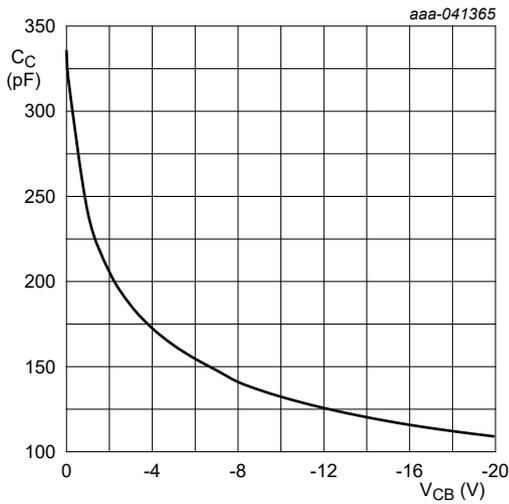
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

Fig. 13. Collector-emitter saturation resistance as a function of collector current; typical values



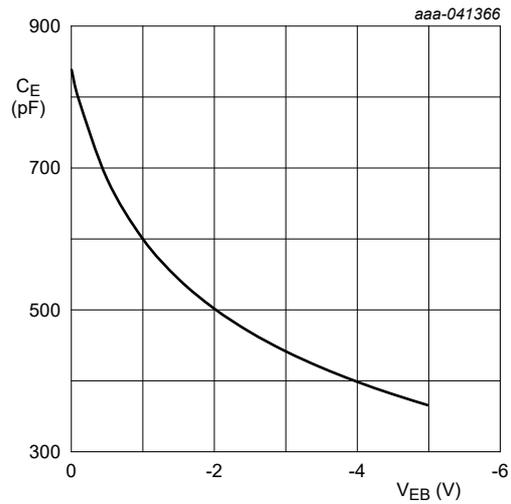
$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 20$   
 (4)  $I_C/I_B = 10$

Fig. 14. Collector-emitter saturation resistance as a function of collector current; typical values



$f = 1\text{ MHz}$   
 $T_{amb} = 25\text{ °C}$

Fig. 15. Collector capacitance as a function of collector-base voltage; typical value



$f = 1\text{ MHz}$   
 $T_{amb} = 25\text{ °C}$

Fig. 16. Emitter capacitance as a function of emitter-base voltage; typical value

### 11. Test information

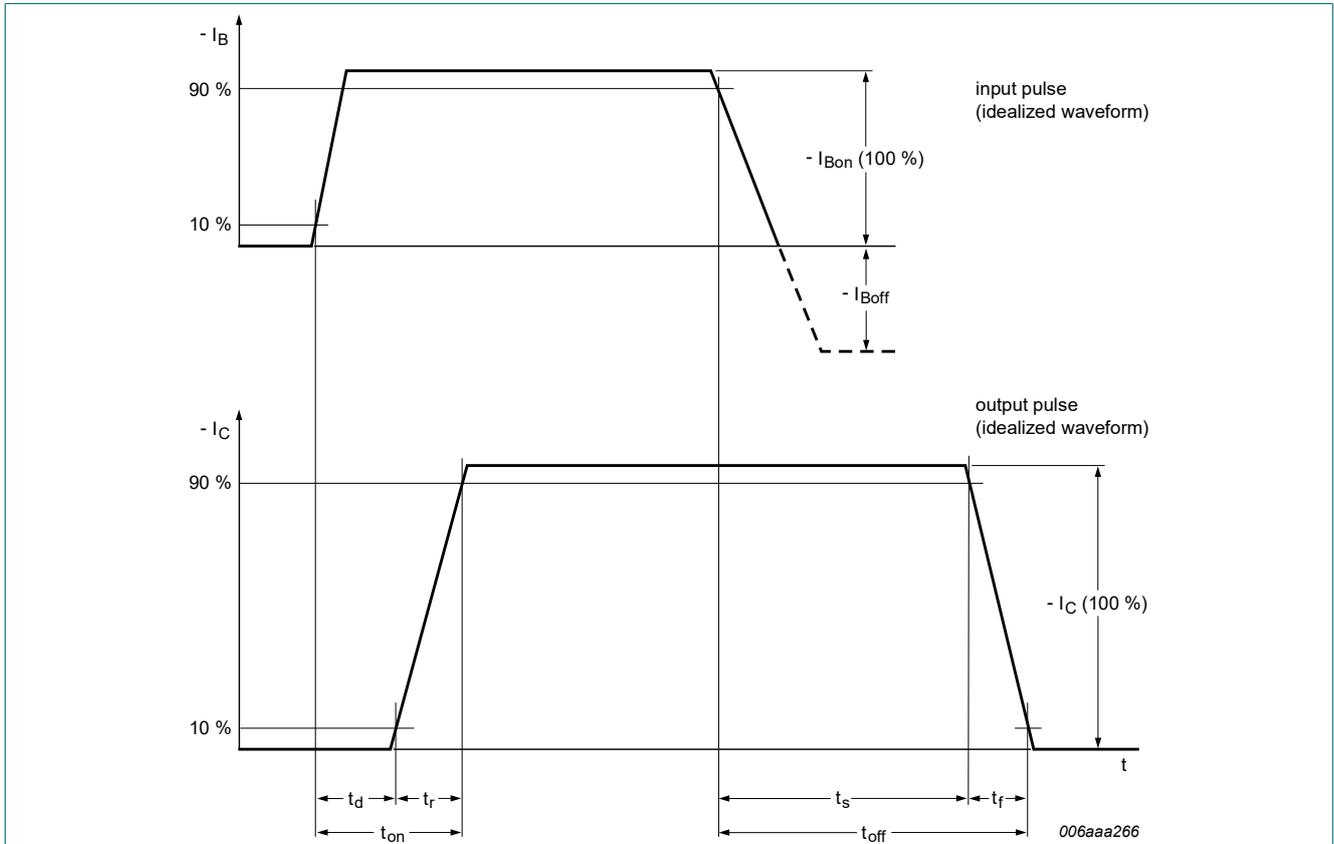


Fig. 17. Transistor switching time definition

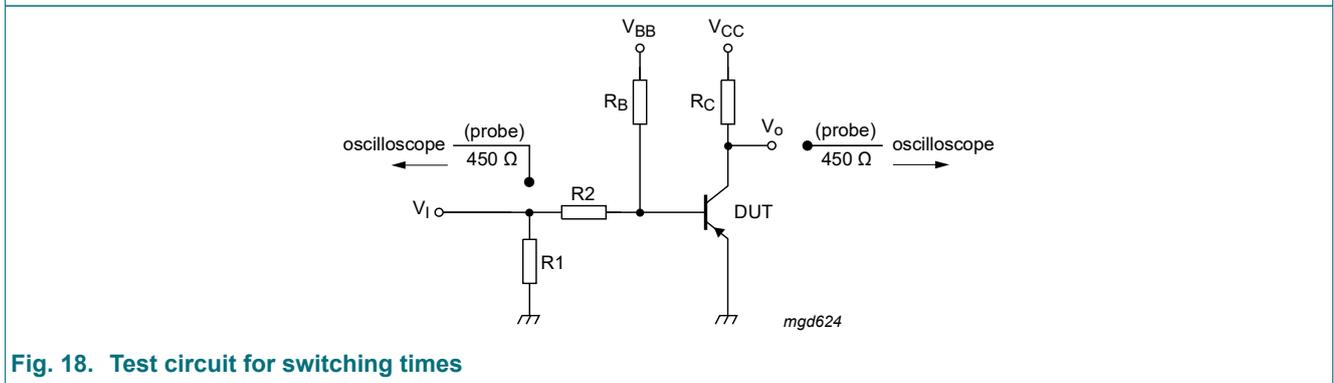


Fig. 18. Test circuit for switching times

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

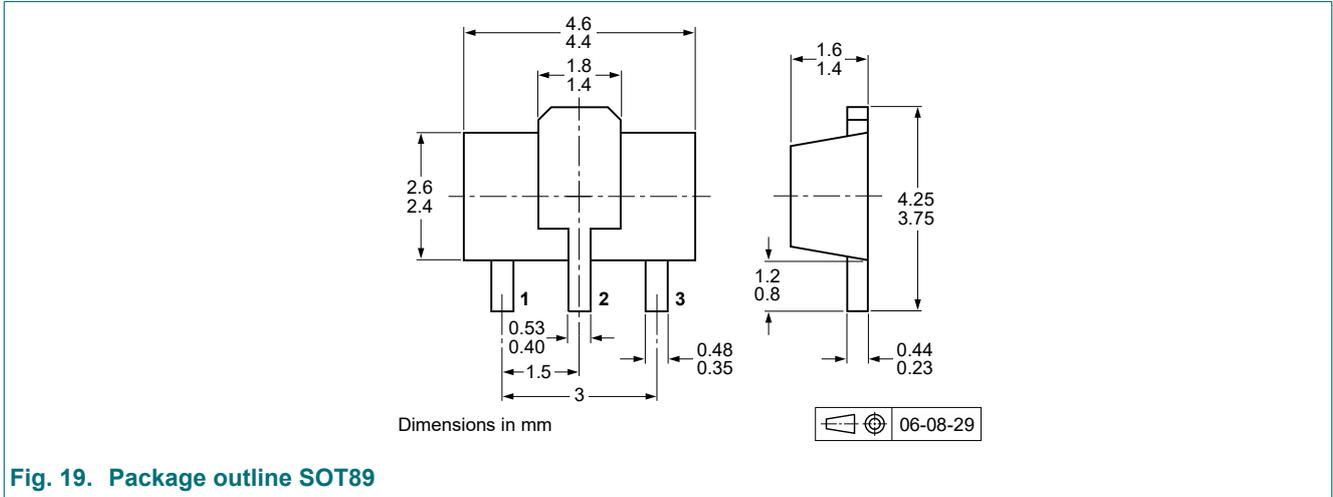


Fig. 19. Package outline SOT89

## 13. Soldering

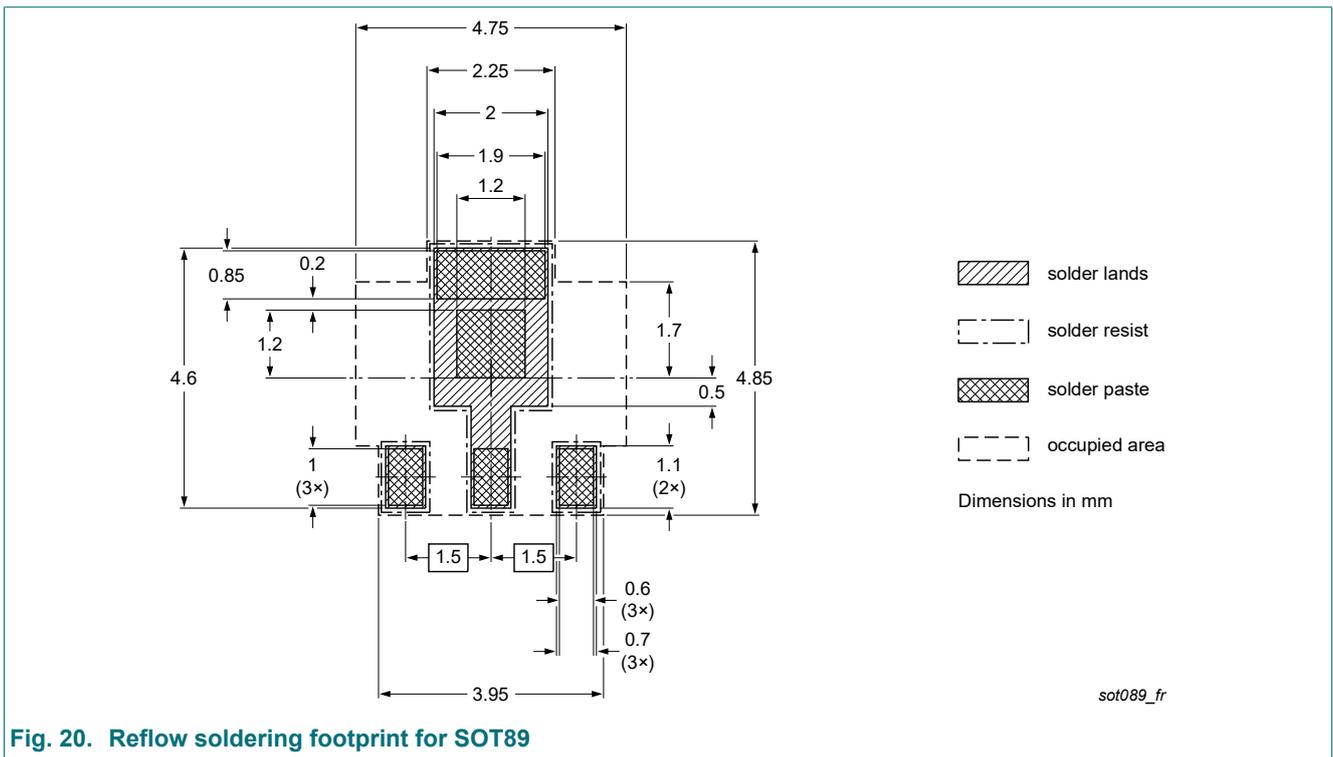


Fig. 20. Reflow soldering footprint for SOT89

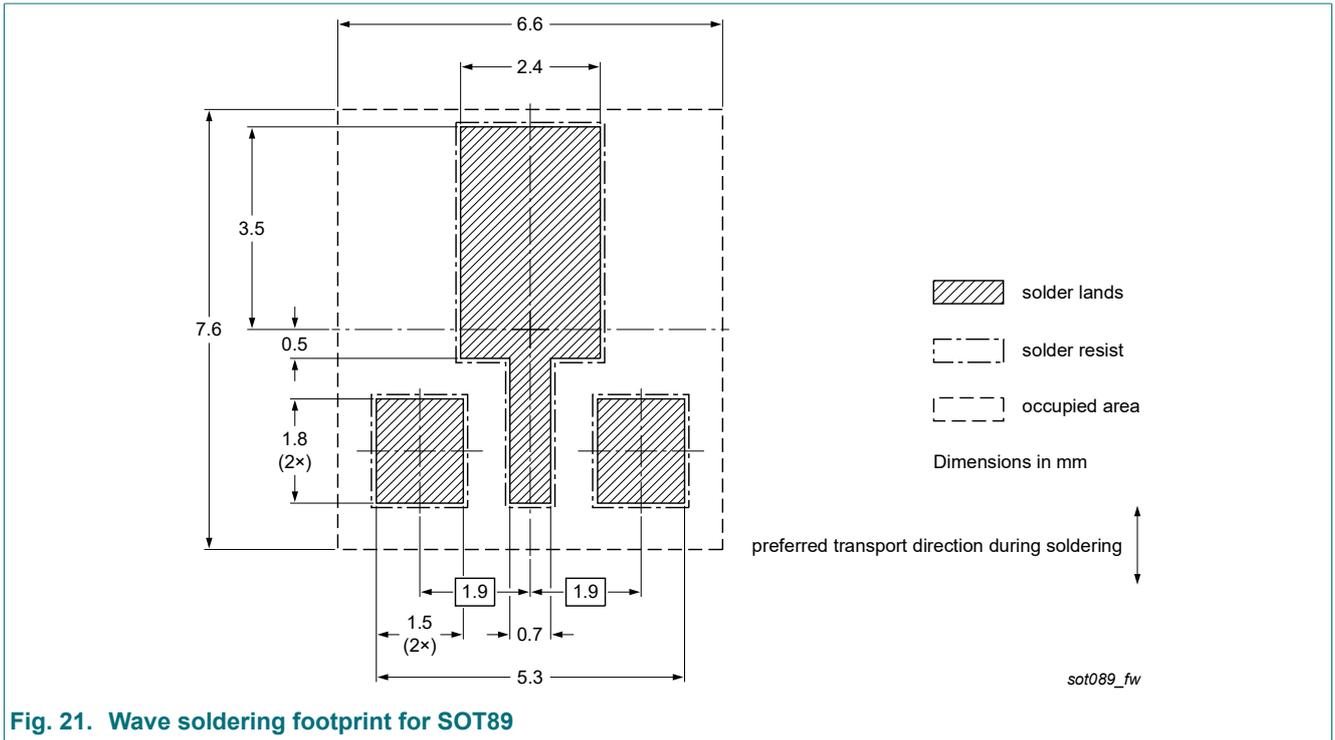


Fig. 21. Wave soldering footprint for SOT89

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4021PX-Q v.2	20250109	Product data sheet	-	PBSS4021PX-Q v.1
Modifications:	• New graphics and values are added.			
PBSS4021PX-Q v.1	20240105	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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